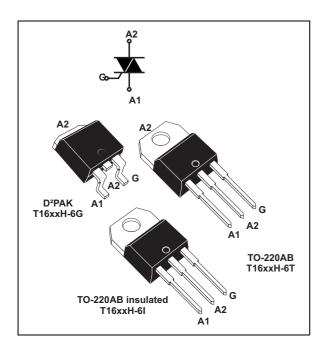


# T1635H, T1650H

## High temperature 16 A Snubberless™ Triacs

Datasheet - production data



### **Features**

- · Medium current Triac
- 150 °C max. T<sub>i</sub> turn-off commutation
- · Low thermal resistance with clip bonding
- · Very high 3 quadrants commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

## **Applications**

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 16 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triacs, according to the high performance at given junction temperatures.

### **Description**

Available in through-hole or surface mount packages, the T1635H and T1650H Triac series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, the T16xxH-6l provides voltage insulation (rated at 2500 V rms).

**Table 1. Device summary** 

Symbol	Value	Unit
I <sub>T(RMS)</sub>	16	А
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V
I <sub>GT</sub>	35 or 50	mA

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Characteristics T1635H, T1650H

## 1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Param	Value	Unit		
	On state rms current (full sine ways)	D <sup>2</sup> PAK, TO-220AB	T <sub>c</sub> = 130 °C	16	۸
I <sub>T(RMS)</sub>	On-state rms current (full sine wave)	TO-220AB Ins	T <sub>c</sub> = 113 °C	10	Α
	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	160	Α
I <sub>TSM</sub>	current (full cycle, T <sub>j</sub> initial = 25 °C)	F = 60 Hz	t = 16.7 ms	168	Α
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		169	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz	T <sub>j</sub> = 150 °C	50	A/µs
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$ $T_j = 150  ^{\circ}C$		4	А	
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 150  ^{\circ}\text{C}$			1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

0	Total and distance			Value		1114
Symbol	Test conditions	Quadrant		T1635H	T1650H	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V}, R_1 = 33 \Omega$	1 - 11 - 111	MAX.	35	50	mA
V <sub>GT</sub>	V <sub>D</sub> = 12 V, N <sub>L</sub> = 33 22	1 - 11 - 111	MAX.	1.0		V
V <sub>GD</sub>	$V_D = V_{DRM}$ , $R_L = 3.3 \text{ k} \Omega$		MIN.	0.15		V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 500 mA		MAX.	35	75	mA
	$I_{L}$ $I_{G} = 1.2 I_{GT}$ $\boxed{ I - III }$		MAX.	50	90	mA
ıL IG =				80	110	
dV/dt (2)	VD = 67% VDRM, gate open, Tj = 150 °C	MIN.	1000	1500	V/µs	
(dl/dt)c (2)	Without snubber, Tj = 150 °C		MIN.	21	28	A/ms

<sup>1.</sup> minimum  $I_{\mbox{\footnotesize GT}}$  is guaranteed at 20% of  $I_{\mbox{\footnotesize GT}}$  max.



<sup>2.</sup> for both polarities of A2 referenced to A1.

T1635H, T1650H Characteristics

**Table 4. Static characteristics** 

Symbol	Test conditions	Value	Unit		
V <sub>T</sub> <sup>(1)</sup>	I <sub>TM</sub> = 23 A, t <sub>p</sub> = 380 μs	T <sub>j</sub> = 25 °C	MAX.	1.5	V
V <sub>t0</sub> (1)	Threshold voltage	T <sub>j</sub> = 150 °C	MAX.	0.80	V
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 150 °C	MAX.	23	mΩ
	V - V	T <sub>j</sub> = 25 °C	MAX.	5	μΑ
I <sub>DRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 150 °C	MAX.	4.1	
I <sub>RRM</sub> <sup>(2)</sup>	$V_D/V_R = 400 \text{ V (at peak mains voltage)}$		MAX.	3.5	mA
	V <sub>D</sub> /V <sub>R</sub> = 200 V (at peak mains voltage)	T <sub>j</sub> = 150 °C	MAX.	3.0	

<sup>1.</sup> for both polarities of A2 referenced to A1

Table 5. Thermal resistance

Symbol	Parameter			Value	Unit
D	lunction to coop (AC)		D <sup>2</sup> PAK / TO-220AB	1.15	
R <sub>th(j-c)</sub>	Junction to case (AC)		TO-220AB Ins	2.1	°C/W
D	lunction to ambient	$S = 1 \text{ cm}^2$	D <sup>2</sup> PAK	45	1 C/VV
↑ th(j-a)	R <sub>th(j-a)</sub> Junction to ambient		TO-220AB / TO-220AB Ins	60	

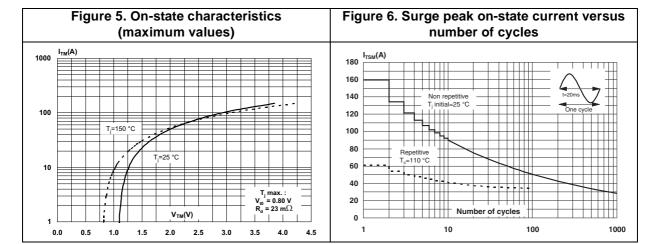
<sup>2.</sup>  $t_p = 380 \,\mu s$ .

**Characteristics** T1635H, T1650H

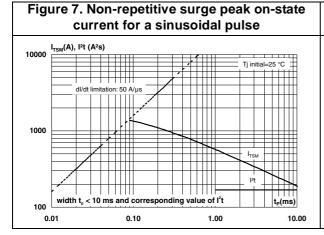
Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle) I<sub>T(RMS)</sub>(A) 18 16 16 14 12 12 10 10 T<sub>c</sub>(°C) 0 25 75

Figure 3. On-state rms current versus ambient Figure 4. Relative variation of thermal impedance versus pulse duration temperature 1.0E+00 Epoxy printed circuit board FR4, 4.0 copper thickness = 35 µm α = 180° -D<sup>2</sup>PAK S<sub>CU</sub>=1 cm<sup>2</sup> TO220AB ins 1.0E-01 TO-220AB 1.0 0.5  $T_{amb}(^{\circ}C)$ t<sub>P</sub>(s) 0.0 25 1.0E-03 1.0E-02 1.0E-01 1.0E+00 1.0E+01 1.0E+02 1.0E+03 75

150



T1635H, T1650H Characteristics



# Figure 8. Relative variation of I<sub>GT</sub>,I<sub>H</sub>, I<sub>L</sub> vs junction temperature(typical values)

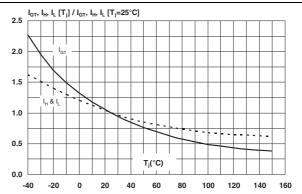


Figure 9. Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c

(dl/dt)<sub>c</sub> [ (dV/dt)<sub>c</sub> ] / Specified (dl/dt)<sub>c</sub> 2.0 typical values 1.8 1.6 1.2 1.0 0.8 0.6 0.4 0.2  $(dV/dt)_{C}(V/\mu s)$ 0.0 0.1 1.0 10.0 100.0

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

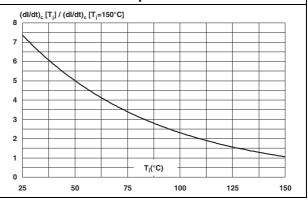


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

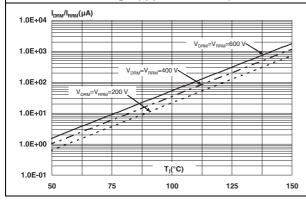
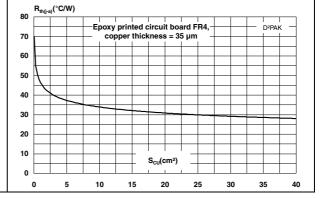


Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab



Package information T1635H, T1650H

## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Recommended torque: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Figure 13. TO-220AB dimension definitions



T1635H, T1650H Package information

Table 6. TO-220AB dimension values

			Dime	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14		1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М		2.60			0.102	

Package information T1635H, T1650H

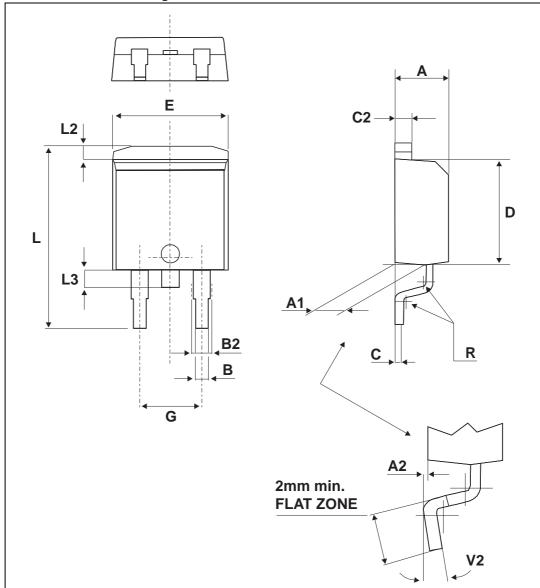


Figure 14. D<sup>2</sup>PAK dimension definitions

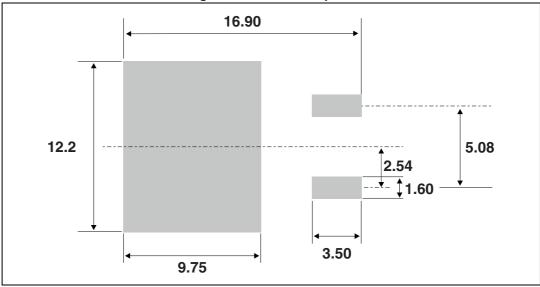


T1635H, T1650H Package information

Table 7. D<sup>2</sup>PAK dimension values

			Dime	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
В	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
С	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R		0.40			0.016	
V2	0°		8°	0°		8°

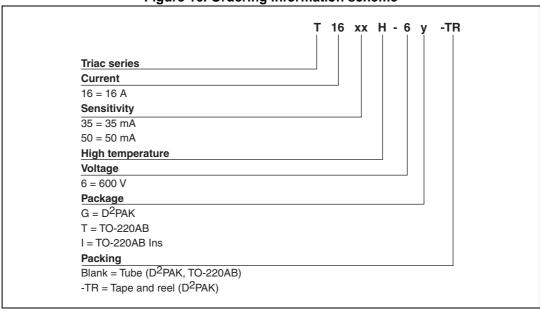
Figure 15. D<sup>2</sup>PAK footprint



Ordering information T1635H, T1650H

## 3 Ordering information

Figure 16. Ordering information scheme



**Table 8. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
T16xxH-6G	T16xxH 6G	D <sup>2</sup> PAK	1.5 g	50	Tube
T16xxH-6G-TR	T16xxH 6G	D <sup>2</sup> PAK	1.5 g	1000	Tape and reel
T16xxH-6T	T16xxH 6T	TO-220AB	2.3 g	50	Tube
T16xxH-6l	T16xxH 6l	TO-220AB Ins	2.3 g	50	Tube

# 4 Revision history

Table 9. Document revision history

Date	Revision	Changes
29-May-2007	1	First issue.
20-Sep-2011	2	Updated: Features, Description and Figure 2.
31-Jan-2014	3	Updated Figure 2, Figure 3, Figure 4, Table 2 and Table 5.



10/11 DocID13566 Rev 3

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